

Data Sheet January 2000 File Number 4050.1

### 4A, 1200V Ultrafast Dual Diode

The RURP4120CC is an ultrafast dual diode with soft recovery characteristics ( $t_{rr}$  < 70ns). It has low forward voltage drop and is silicon nitride passivated ion-implanted epitaxial planar construction.

This device is intended for use as a freewheeling/clamping diode and rectifier in a variety of switching power supplies and other power switching applications. Its low stored charge and ultrafast soft recovery minimize ringing and electrical noise in many power switching circuits reducing power loss in the switching transistors.

Formerly developmental type TA49036.

# **Ordering Information**

PART NUMBER	PACKAGE	BRAND
RURP4120CC	TO-220AB	RUR4120C

NOTE: When ordering, use the entire part number.

# Symbol



### **Features**

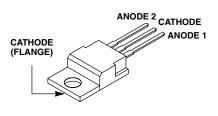
- · Avalanche Energy Rated
- · Planar Construction

### **Applications**

- · Switching Power Supplies
- · Power Switching Circuits
- · General Purpose

## Packaging

JEDEC TO-220AB



#### Absolute Maximum Ratings (Per Leg) T<sub>C</sub> = 25°C, Unless Otherwise Specified RURP4120CC UNITS 1200 V Working Peak Reverse Voltage ...... V<sub>RWM</sub> 1200 DC Blocking Voltage .....V<sub>B</sub> 1200 4 $T_{\rm C} = 152^{\rm o}{\rm C}$ Repetitive Peak Surge Current ...... I<sub>FRM</sub> 8 Α Square Wave, 20kHz 40 Α Halfwave, 1 Phase, 60Hz 50 W 10 mJ -65 to 175 °C

### RURP4120CC

**Electrical Specifications** (Per Leg) T<sub>C</sub> = 25°C, Unless Otherwise Specified

SYMBOL	TEST CONDITION	MIN	TYP	MAX	UNITS
V <sub>F</sub>	I <sub>F</sub> = 4A	-	-	2.1	V
	$I_F = 4A, T_C = 150^{\circ}C$	-	-	1.9	V
I <sub>R</sub>	V <sub>R</sub> = 1200V	-	-	100	μА
	$V_R = 1200V, T_C = 150^{\circ}C$	-	-	500	μА
t <sub>rr</sub>	$I_F = 1A$ , $dI_F/dt = 200A/\mu s$	-	-	70	ns
	$I_F = 4A$ , $dI_F/dt = 200A/\mu s$	-	-	90	ns
t <sub>a</sub>	$I_F = 4A$ , $dI_F/dt = 200A/\mu s$	-	40	-	ns
t <sub>b</sub>	$I_F = 4A$ , $dI_F/dt = 200A/\mu s$	-	28	-	ns
Q <sub>RR</sub>	$I_F = 4A$ , $dI_F/dt = 200A/\mu s$	-	335	-	nC
СЈ	V <sub>R</sub> = 10V, I <sub>F</sub> = 0A	-	15	-	pF
$R_{ heta JC}$		-	-	3	°C/W

#### **DEFINITIONS**

 $V_F$  = Instantaneous forward voltage (pw = 300 $\mu$ s, D = 2%).

 $I_R$  = Instantaneous reverse current.

 $t_{rr}$  = Reverse recovery time (See Figure 9), summation of  $t_a$  +  $t_b$ .

t<sub>a</sub> = Time to reach peak reverse current (See Figure 9).

t<sub>b</sub> = Time from peak I<sub>RM</sub> to projected zero crossing of I<sub>RM</sub> based on a straight line from peak I<sub>RM</sub> through 25% of I<sub>RM</sub> (See Figure 9).

Q<sub>RR</sub> = Reverse recovery charge.

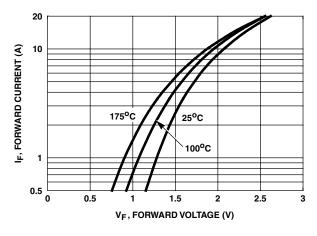
 $C_J$  = Junction Capacitance.

 $R_{\theta,JC}$  = Thermal resistance junction to case.

pw = Pulse width.

D = Duty cycle.

# **Typical Performance Curves**





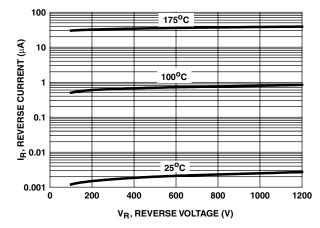


FIGURE 2. REVERSE CURRENT vs REVERSE VOLTAGE

## Typical Performance Curves (Continued)

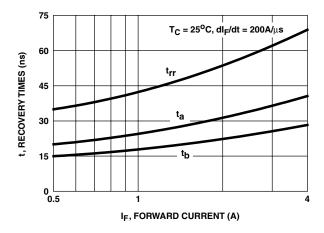


FIGURE 3.  $t_{rr}$ ,  $t_a$  and  $t_b$  curves vs forward current

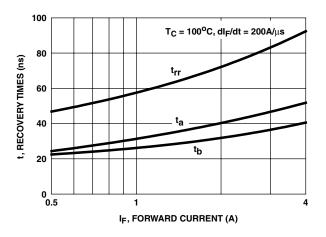


FIGURE 4.  $t_{rr}$ ,  $t_a$  and  $t_b$  curves vs forward current

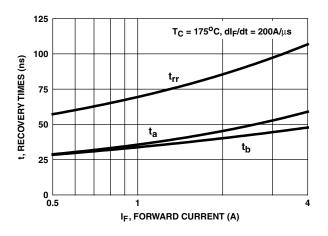


FIGURE 5.  $t_{rr}$ ,  $t_a$  and  $t_b$  curves vs forward current

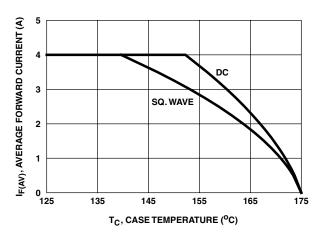


FIGURE 6. CURRENT DERATING CURVE

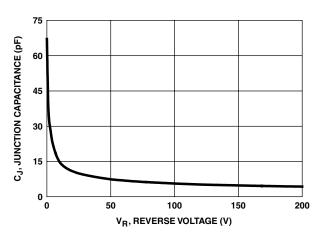


FIGURE 7. JUNCTION CAPACITANCE vs REVERSE VOLTAGE

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# Test Circuits and Waveforms

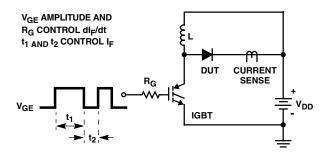


FIGURE 8. t<sub>rr</sub> TEST CIRCUIT

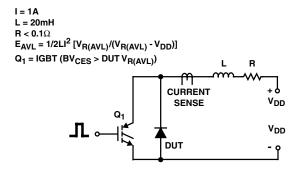


FIGURE 10. AVALANCHE ENERGY TEST CIRCUIT

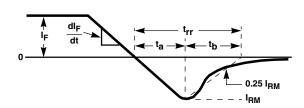


FIGURE 9. t<sub>rr</sub> WAVEFORMS AND DEFINITIONS

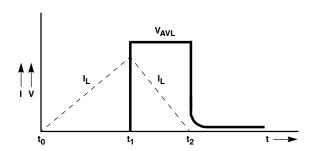


FIGURE 11. AVALANCHE CURRENT AND VOLTAGE WAVEFORMS

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CROSSVOLT <sup>TM</sup>	GTO™ .	QFET™	SyncFET™
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E <sup>2</sup> CMOS <sup>TM</sup>	MicroFET™	SILENT SWITCHER ®	$VCX^{TM}$
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Datasheet Identification	Product Status	Definition
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